



### 3.3V CMOS 9-BIT BUS-INTERFACE FLIP-FLOP WITH 3-STATE OUTPUTS AND 5 VOLT TOLERANT I/O

IDT74LVC823A

#### FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- Rail-to-rail output swing for increased noise margin
- All inputs, outputs, and I/O are 5V tolerant
- Supports hot insertion
- Available in SSOP, QSOP, and TSSOP packages

#### DRIVE FEATURES:

- High Output Drivers: ±24mA
- Reduced system switching noise

#### APPLICATIONS:

- 3.3V high speed systems
- 3.3V and lower voltage computing systems

#### DESCRIPTION:

The LVC823A 9-bit bus-interface flip-flop is built using advanced dual metal CMOS technology. The LVC823A device is designed specifically for driving highly capacitive or relatively low-impedance loads. The device is particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

With the clock-enable ( $\overline{\text{CLKEN}}$ ) input low, the nine D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking  $\overline{\text{CLKEN}}$  high disables the clock buffer, latching the outputs. This device has noninverting data (D) inputs. Taking the clear ( $\overline{\text{CLR}}$ ) input low causes the nine Q outputs to go low, independently of the clock.

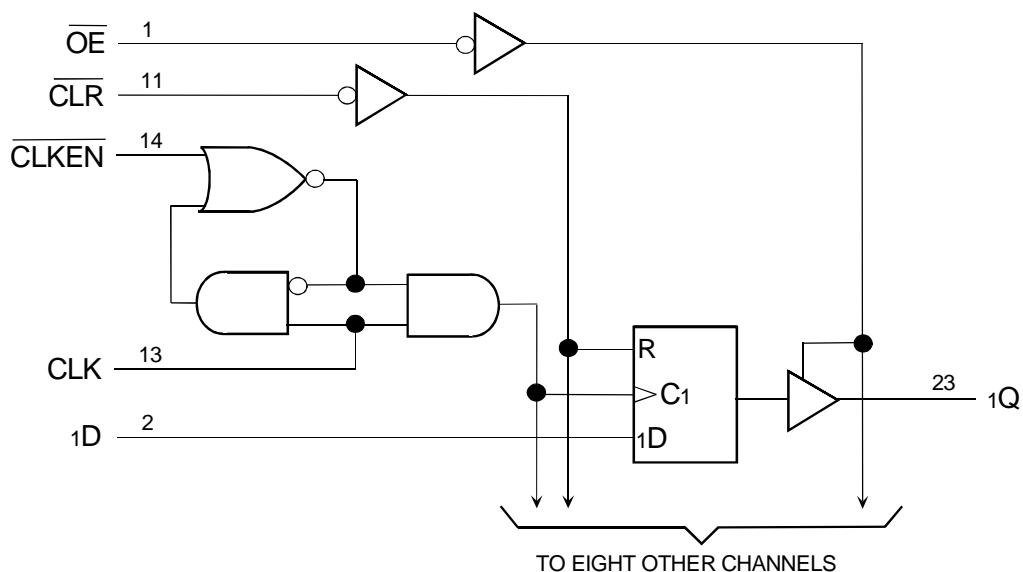
A buffered output-enable ( $\overline{\text{OE}}$ ) input can be used to place the nine outputs in either a normal logic state (high or low logic levels) or a high-impedance state.  $\overline{\text{OE}}$  does not affect internal operations of the latch. Previously stored data can be retained or new data can be entered while the outputs are in the high-impedance state.

The LVC823A has been designed with a ±24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

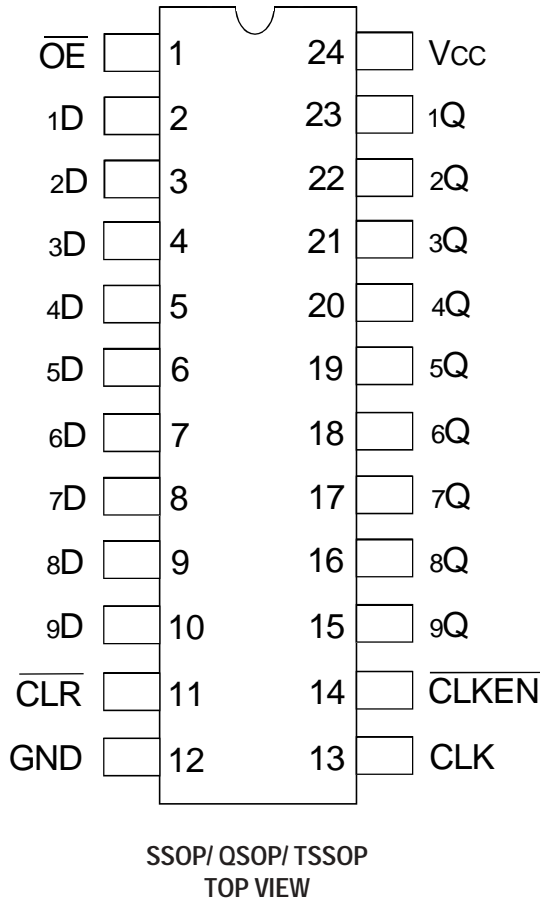
To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

#### FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
V <sub>TERM</sub>	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
I <sub>OUT</sub>	DC Output Current	-50 to +50	mA
I <sub>IK</sub> I <sub>OK</sub>	Continuous Clamp Current, V <sub>I</sub> < 0 or V <sub>O</sub> < 0	-50	mA
I <sub>CC</sub> I <sub>SS</sub>	Continuous Current through each V <sub>CC</sub> or GND	±100	mA

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (T<sub>A</sub> = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Typ.	Max.	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V	4.5	6	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V	5.5	8	pF
C <sub>I/O</sub>	I/O Port Capacitance	V <sub>IN</sub> = 0V	6.5	8	pF

NOTE:

- As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
$\overline{OE}$	Output Enable Input (Active LOW)
CLK	Clock Input
$\overline{CLKEN}$	Clock Enable Input (Active LOW)
$\overline{CLR}$	Clear Input (Active LOW)
xD	Data Inputs
xQ	Data Outputs

FUNCTION TABLE (EACH FLIP-FLOP)<sup>(1)</sup>

Inputs					Outputs
$\overline{OE}$	$\overline{CLR}$	$\overline{CLKEN}$	CLK	xD	xQ
L	L	X	X	X	L
L	H	L	↑	H	H
L	H	L	↑	L	L
L	H	H	X	X	Q <sup>(2)</sup>
H	X	X	X	X	Z

NOTES:

- H = HIGH Voltage Level  
L = LOW Voltage Level  
X = Don't Care  
Z = High Impedance  
↑ = LOW-to-HIGH transition
- Output level before indicated steady-state input conditions were established.

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage Level	VCC = 2.3V to 2.7V		1.7	—	—	V
		VCC = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	VCC = 2.3V to 2.7V		—	—	0.7	V
		VCC = 2.7V to 3.6V		—	—	0.8	
IIH IIL	Input Leakage Current	VCC = 3.6V	VI = 0 to 5.5V	—	—	±5	µA
IOZH IOZL	High Impedance Output Current (3-State Output pins)	VCC = 3.6V	VO = 0 to 5.5V	—	—	±10	µA
IOFF	Input/Output Power Off Leakage	VCC = 0V, VIN or VO ≤ 5.5V		—	—	±50	µA
VIK	Clamp Diode Voltage	VCC = 2.3V, IIN = -18mA		—	-0.7	-1.2	V
VH	Input Hysteresis	VCC = 3.3V		—	100	—	mV
ICCL ICCH IC CZ	Quiescent Power Supply Current	VCC = 3.6V	VIN = GND or VCC	—	—	10	µA
			3.6 ≤ VIN ≤ 5.5V <sup>(2)</sup>	—	—	10	
ΔICC	Quiescent Power Supply Current Variation	One input at VCC - 0.6V, other inputs at VCC or GND		—	—	500	µA

### NOTES:

1. Typical values are at VCC = 3.3V, +25°C ambient.
2. This applies in the disabled state only.

## OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	IOH = -0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	IOH = -6mA	2	—	
		VCC = 2.3V	IOH = -12mA	1.7	—	
		VCC = 2.7V		2.2	—	
		VCC = 3V		2.4	—	
		VCC = 3V	IOH = -24mA	2.2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		VCC = 2.3V	IOL = 6mA	—	0.4	
			IOL = 12mA	—	0.7	
		VCC = 2.7V	IOL = 12mA	—	0.4	
		VCC = 3V	IOL = 24mA	—	0.55	

### NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate VCC range. TA = -40°C to +85°C.

OPERATING CHARACTERISTICS,  $V_{CC} = 3.3V \pm 0.3V$ ,  $T_A = 25^\circ C$ 

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Flip-Flop Outputs enabled	CL = 0pF, f = 10MHz	59	pF
CPD	Power Dissipation Capacitance per Flip-Flop Outputs disabled		46	

SWITCHING CHARACTERISTICS<sup>(1)</sup>

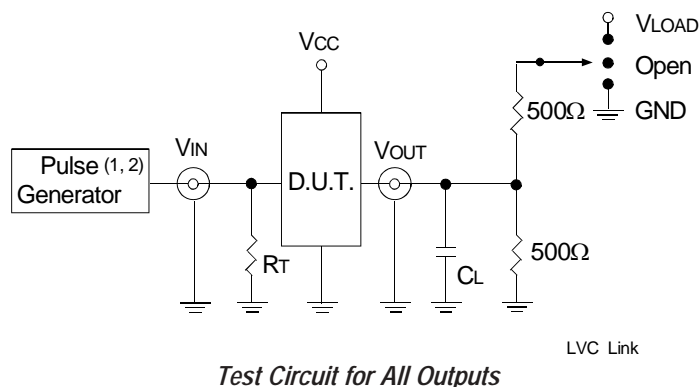
Symbol	Parameter	V <sub>CC</sub> = 2.7V		V <sub>CC</sub> = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	
f <sub>MAX</sub>		150	—	150	—	MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay CLK to xQ	—	8.9	1.4	8	ns
t <sub>PHL</sub>	Propagation Delay $\overline{CLR}$ to xQ	—	8.8	2.5	7.9	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time $\overline{OE}$ to xQ	—	8.3	1.6	7.2	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time $\overline{OE}$ to xQ	—	7.1	1.1	6	ns
t <sub>w</sub>	Pulse Duration, $\overline{CLR}$ LOW	3.3	—	3.3	—	ns
t <sub>w</sub>	Pulse Duration, CLK HIGH or LOW	3.3	—	3.3	—	ns
t <sub>SU</sub>	Set-up Time, $\overline{CLR}$ inactive before CLK $\uparrow$	1	—	1	—	ns
t <sub>SU</sub>	Set-up Time, data before CLK $\uparrow$	1.3	—	1.3	—	ns
t <sub>SU</sub>	Set-up Time, $\overline{CLKEN}$ LOW before CLK $\uparrow$	1.8	—	1.8	—	ns
t <sub>H</sub>	Hold Time, data after CLK $\uparrow$	2	—	2	—	ns
t <sub>H</sub>	Hold Time, $\overline{CLKEN}$ LOW after CLK $\uparrow$	1.3	—	1.3	—	ns
t <sub>SK(0)</sub>	Output Skew <sup>(2)</sup>	—	—	—	1	ns

## NOTES:

- See TEST CIRCUITS AND WAVEFORMS.  $T_A = -40^\circ C$  to  $+85^\circ C$ .
- Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS  
TEST CONDITIONS

Symbol	V <sub>CC</sub> <sup>(1)</sup> =3.3V±0.3V	V <sub>CC</sub> <sup>(1)</sup> =2.7V	V <sub>CC</sub> <sup>(2)</sup> =2.5V±0.2V	Unit
V <sub>LOAD</sub>	6	6	2 x V <sub>CC</sub>	V
V <sub>IH</sub>	2.7	2.7	V <sub>CC</sub>	V
V <sub>T</sub>	1.5	1.5	V <sub>CC</sub> / 2	V
V <sub>LZ</sub>	300	300	150	mV
V <sub>HZ</sub>	300	300	150	mV
C <sub>L</sub>	50	50	30	pF



**DEFINITIONS:**

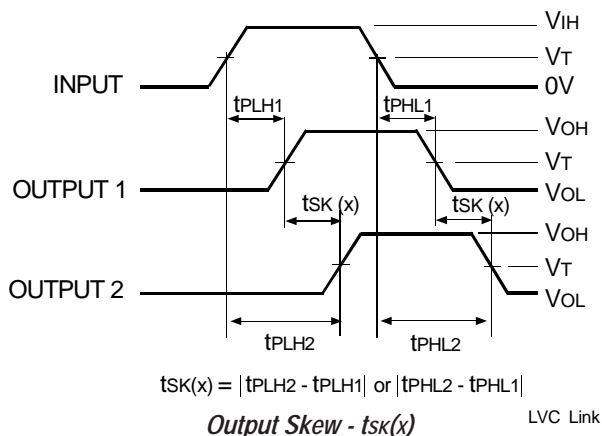
C<sub>L</sub> = Load capacitance: includes jig and probe capacitance.  
R<sub>T</sub> = Termination resistance: should be equal to Z<sub>OUT</sub> of the Pulse Generator.

**NOTES:**

1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t<sub>r</sub> ≤ 2.5ns; t<sub>r</sub> ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t<sub>r</sub> ≤ 2ns; t<sub>r</sub> ≤ 2ns.

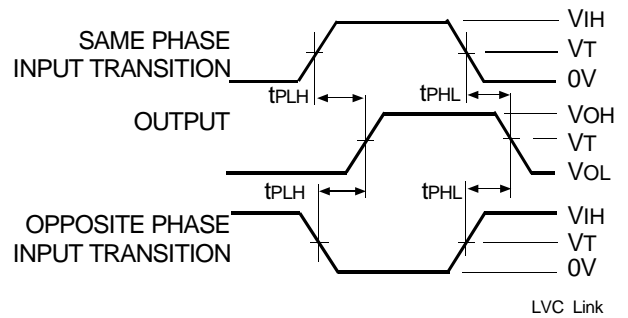
**SWITCH POSITION**

Test	Switch
Open Drain Disable Low Enable Low	V <sub>LOAD</sub>
Disable High Enable High	GND
All Other Tests	Open

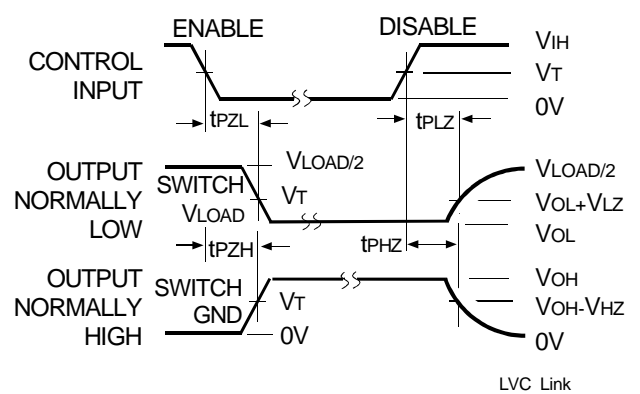


**NOTES:**

1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



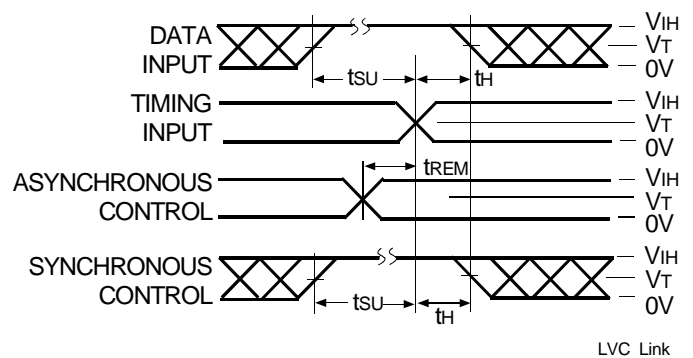
**Propagation Delay**



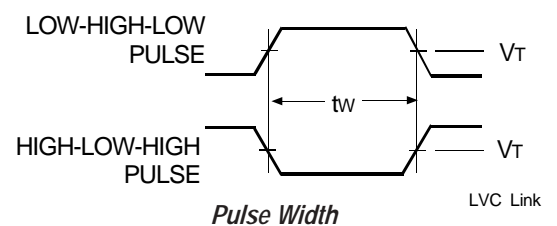
**Enable and Disable Times**

**NOTE:**

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



**Set-up, Hold, and Release Times**



## ORDERING INFORMATION

IDT	XX	LVC	X	XXXX	XX	
Temp. Range	Bus-Hold	Device Type	Package			
					PY	Shrink Small Outline Package
					Q	Quarter Size Small Outline Package
					PG	Thin Shrink Small Outline Package
				823A		9-Bit Bus-Interface Flip-Flop with 3-State Outputs, $\pm 24\text{mA}$
				Blank		No Bus-hold
				74		$-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$



**CORPORATE HEADQUARTERS**  
2975 Stender Way  
Santa Clara, CA 95054

**for SALES:**  
800-345-7015 or 408-727-6116  
fax: 408-492-8674  
www.idt.com

**for Tech Support:**  
logichelp@idt.com  
(408) 654-6459